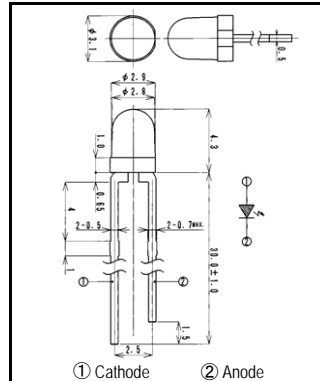
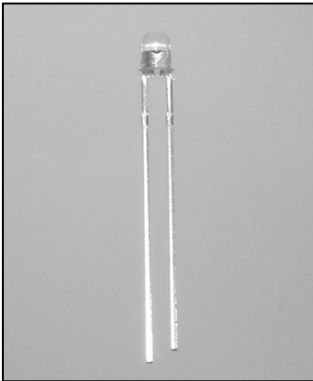


# MT5066A-UR2

## Visible Light Emitting Diode



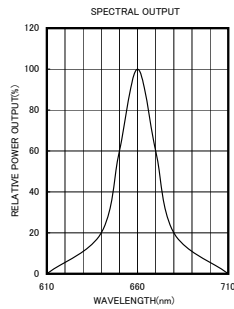
- FEATURES**
- High-output Power
  - Compact
  - High Reliability
- APPLICATIONS**
- Optical Switches
  - Optical Sensors

### 1. ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

ITEM	SYMBOL	RATINGS	UNIT
Forward Current (DC)	IF	50	mA
Forward Current (Pulse)*1	IFP	0.5	A
Reverse Voltage	VR	5	V
Power Dissipation	PD	110	mW
Operating Temp.	Topr	-20 TO 80	°C
Storage Temp.	Tstg	-30 TO 100	°C
Junction Temp.	TJ	100	°C
Lead Soldering Temp.*2	Tls	260	°C

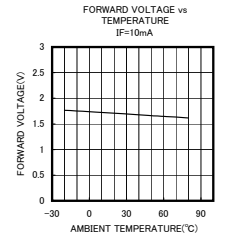
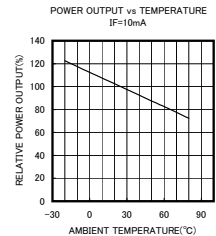
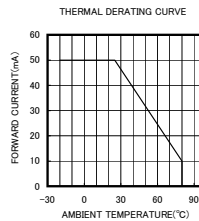
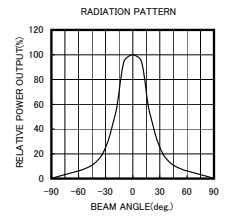
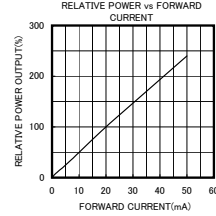
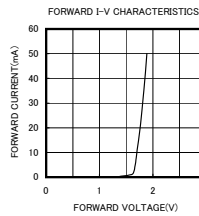
\*1:Tw=10uS,T=10mS

\*2:Time 5 Sec max,Position:Up to 3mm from the body



### 2. ELECTRICAL & OPTICAL CHARACTERISTICS (Ta=25°C)

ITEM	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Power Output	PO	IF=20mA	5.0	7.0		mW
Forward Voltage	VF	IF=20mA		1.8	2.2	V
Reverse Current	IR	VR=5V			100	μA
Peak Wavelength	λp	IF=20mA		660		nm
Spectral Line Half Width	Δλ	IF=20mA		25		nm
Half Intensity Beam Angle	θ	IF=20mA		±18		deg.
Rise Time	Tr	IFP=20mA		30		nS
Fall Time	Tf	IFP=20mA		30		nS
Junction Capacitance	Cj	1MHz,V=0V		20		pF
Temp. Coefficient of PO	P/T	IF=10mA		-0.5		%/°C
Temp. Coefficient of VF	V/T	IF=10mA		-1.5		mV/°C



To purchase this part contact  
Marktech Optoelectronics at  
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